VT1045CBP

Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.34$ V at $I_F = 2.5$ A



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| PRIMARY CHARACTERISTICS | | | | | |
|--|-----------|--|--|--|--|
| I _{F(AV)} | 2 x 5.0 A | | | | |
| V _{RRM} | 45 V | | | | |
| I _{FSM} | 100 A | | | | |
| V_F at $I_F = 5.0$ A | 0.41 V | | | | |
| T _{OP} max. (AC mode) | 150 °C | | | | |
| T _J max. (DC forward current) | 200 °C | | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- T_{.1} 200 °C max. in solar bypass mode application
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|---|------------|-------------------------------------|---------------|------|--|
| PARAMETER | | SYMBOL | VT1045CBP | UNIT | |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 45 | V | |
| Maximum average forward rectified current (fig. 1) | per device | - I _{F(AV)} ⁽¹⁾ | 10 | A | |
| | per diode | | 5.0 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 100 | А | |
| Operating junction and storage temperature range (AC mode) | | T _{OP} , T _{STG} | - 40 to + 150 | °C | |
| Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$ | | T _J ⁽²⁾ | ≤ 200 | °C | |

Notes

⁽¹⁾ With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

1

Pb

ROHS COMPLIANT

HALOGEN

VT1045CBP



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|--|---------------------------|-------------------------------|------|------|------|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode | I _F = 2.5 A | - T _A = 25 °C | V _F ⁽¹⁾ | 0.44 | - | V |
| | I _F = 5.0 A | | | 0.49 | 0.58 | |
| | I _F = 2.5 A | - T _A = 125 °C | | 0.34 | - | |
| | $I_{F} = 5.0 \text{ A}$ | | | 0.41 | 0.50 | |
| Reverse current per diode | V _B = 45 V T _A = 25 °C | T _A = 25 °C | I _R ⁽²⁾ | - | 500 | μA |
| | v _R = 43 v | T _A = 125 °C | | 5 | 15 | mA |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|--|------------|---------------------|-----------|------|--|
| PARAMETER | | SYMBOL | VT1045CBP | UNIT | |
| Typical thermal resistance | per diode | $R_{	ext{	heta}JC}$ | 3.5 | °C/W | |
| | per device | | 2.5 | C/W | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|-----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | VT1045CBP-M3/4W | 1.87 | 4W | 50/tube | Tube | |

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

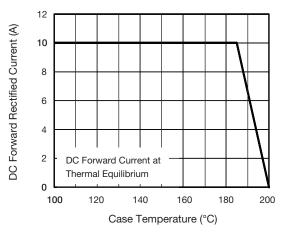


Fig. 1 - Maximum Forward Current Derating Curve

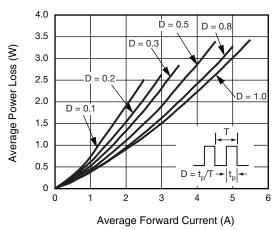
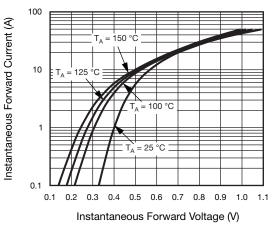


Fig. 2 - Forward Power Loss Characteristics Per Diode

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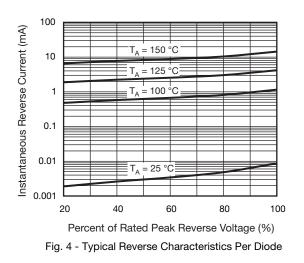
VT1045CBP

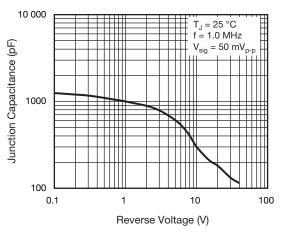


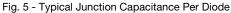


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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode







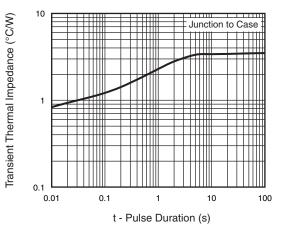
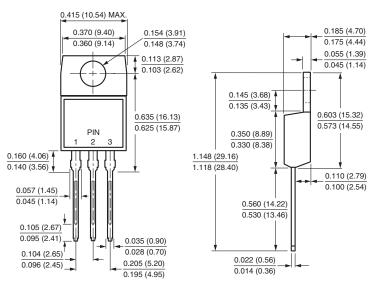


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters) TO-220AB



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